# NSN 5961-01-057-3305

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**Inclosure Material:** 

Metal

**Overall Length:** 

Between 0.293 inches and 0.357 inches

**Terminal Length:** 

Between 1.000 inches and 1.625 inches

**Overall Diameter:** 

Between 0.215 inches and 0.235 inches

#### **End Application:**

Central office, telephone auto; aircraft, ailifter c-17a; support equipment, b-52 aircraft; aircraft, ac-130h, mc-130h, ec-130e, hc-130; regency net system (an/trc-179 (v), an/frc-180 (v), an/grc-215); helicopter, carrier based asw, sh-60f; an/uyk- (v) sonar/fire control tactical computer; support equipment, b-1 aircraft; usns stalwart class tagos; guided missile system; ram ex43

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-13

**Mounting Method:** 

Terminal

**Features Provided:** 

Hermetically sealed case

**Criticality Code Justification:** 

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

231.0 breakdown voltage, dc

**Current Rating Per Characteristic:** 

4.60 amperes forward current, average horsepower metric

**Power Rating Per Characteristic:** 

1500.0 watts small-signal input power, common-collector pascal

#### **Maximum Operating Tempurature Per Measurement Point:**

175.0 degrees celsius ambient air

**Special Features:** 

Weapon system essential; junction pattern arrangement: pn

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Terminal Type And Quantity:**

2 insulated wire lead

## **Specification Data:**

81349-mil-s-19500/507 government specification

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

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